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Jameco Part Number 2035645



STPS30L30CT/CG/CR

LOW DROP POWER SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

| | |
|-------------|-----------------|
| $I_{F(AV)}$ | 2 x 15 A |
| V_{RRM} | 30 V |
| $T_j(max)$ | 150 °C |
| $V_F(max)$ | 0.37 V |

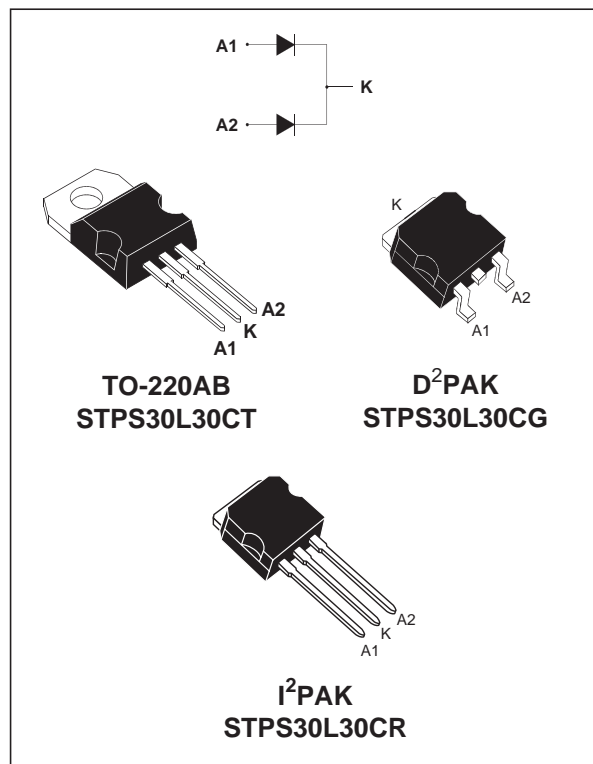
FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING
- LOW FORWARD VOLTAGE DROP
- LOW THERMAL RESISTANCE
- AVALANCHE CAPABILITY SPECIFIED

DESCRIPTION

Dual center tap Schottky rectifiers suited for Switch Mode Power Supply and high frequency DC to DC converters.

Packaged in TO-220AB, D²PAK and I²PAK, these devices are intended for use in low voltage, high frequency inverters, free-wheeling and polarity protection applications.



ABSOLUTE RATINGS (limiting values, per diode)

| Symbol | Parameter | | Value | Unit |
|--------------|--|--|-------------------------------------|------------------|
| V_{RRM} | Repetitive peak reverse voltage | | 30 | V |
| $I_{F(RMS)}$ | RMS forward current | | 30 | A |
| $I_{F(AV)}$ | Average forward current | $T_c = 140^\circ\text{C}$ $\delta = 0.5$ | Per diode 15 Per device 30 | A |
| I_{FSM} | Surge non repetitive forward current | $t_p = 10 \text{ ms}$ Sinusoidal | 220 | A |
| I_{RRM} | Peak repetitive reverse current | $t_p = 2 \mu\text{s}$ $F = 1\text{kHz}$ square | 1 | A |
| I_{RSM} | Non repetitive peak reverse current | $t_p = 100\mu\text{s}$ square | 3 | A |
| P_{ARM} | Repetitive peak avalanche power | $t_p = 1\mu\text{s}$ $T_j = 25^\circ\text{C}$ | 5300 | W |
| T_{stg} | Storage temperature range | | - 65 to + 150 | °C |
| T_j | Maximum operating junction temperature * | | 150 | °C |
| dV/dt | Critical rate of rise reverse voltage | | 10000 | V/ μs |

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THERMAL RESISTANCE

| Symbol | Parameter | | Value | Unit |
|---------------|------------------|-----------|-------|-----------------------------|
| $R_{th(j-c)}$ | Junction to case | Per diode | 1.5 | $^{\circ}\text{C}/\text{W}$ |
| | | Total | 0.8 | |
| $R_{th(c)}$ | | Coupling | 0.1 | $^{\circ}\text{C}/\text{W}$ |

When the diodes 1 and 2 are used simultaneously :
 $\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$

STATIC ELECTRICAL CHARACTERISTICS (per diode)

| Symbol | Parameter | Tests Conditions | | Min. | Typ. | Max. | Unit |
|---------|-------------------------|-----------------------------|---------------------|------|------|------|------|
| I_R^* | Reverse leakage current | $T_j = 25^{\circ}\text{C}$ | $V_R = V_{RRM}$ | | | 1.5 | mA |
| | | $T_j = 125^{\circ}\text{C}$ | | | 170 | 350 | mA |
| V_F^* | Forward voltage drop | $T_j = 25^{\circ}\text{C}$ | $I_F = 15\text{ A}$ | | | 0.46 | V |
| | | $T_j = 125^{\circ}\text{C}$ | $I_F = 15\text{ A}$ | | 0.33 | 0.37 | |
| | | $T_j = 25^{\circ}\text{C}$ | $I_F = 30\text{ A}$ | | | 0.57 | |
| | | $T_j = 125^{\circ}\text{C}$ | $I_F = 30\text{ A}$ | | 0.43 | 0.5 | |

Pulse test : * $t_p = 380\ \mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation :
 $P = 0.24 \times I_{F(AV)} + 0.009 I_{F(RMS)}^2$

Fig. 1: Average forward power dissipation versus average forward current (per diode).

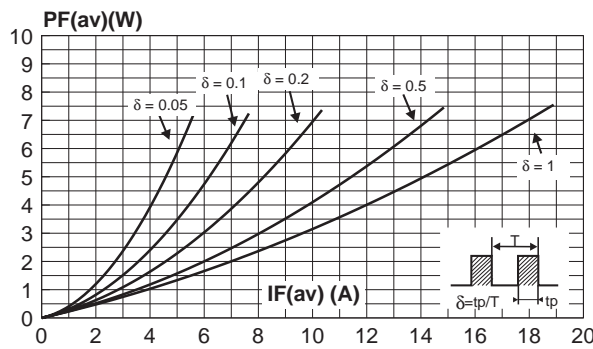


Fig. 3: Normalized avalanche power derating versus pulse duration.

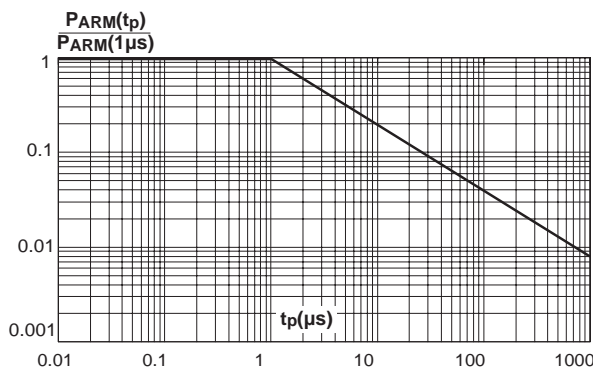


Fig. 2: Average current versus ambient temperature ($\delta=0.5$) (per diode).

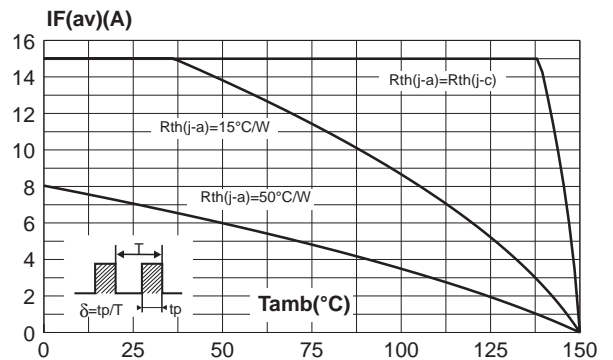


Fig. 4: Normalized avalanche power derating versus junction temperature.

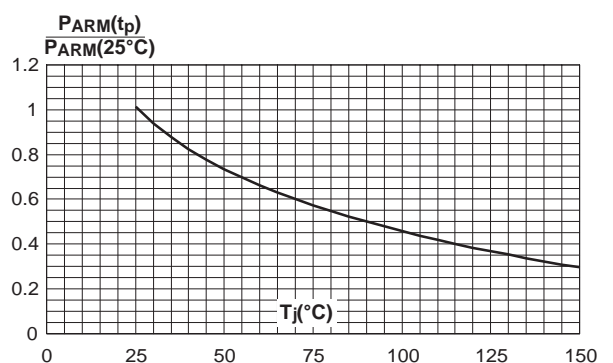


Fig. 4: Non repetitive surge peak forward current versus overload duration (maximum values) (per diode).

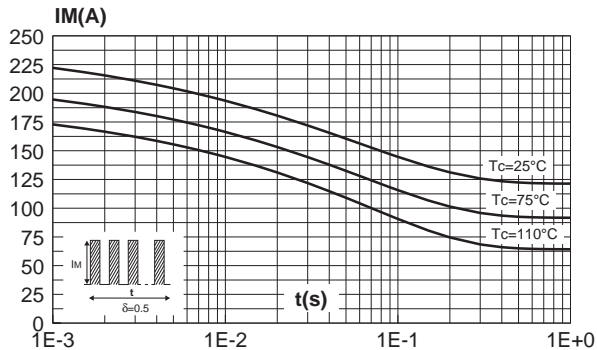


Fig. 5: Relative variation of thermal transient impedance junction to case versus pulse duration.

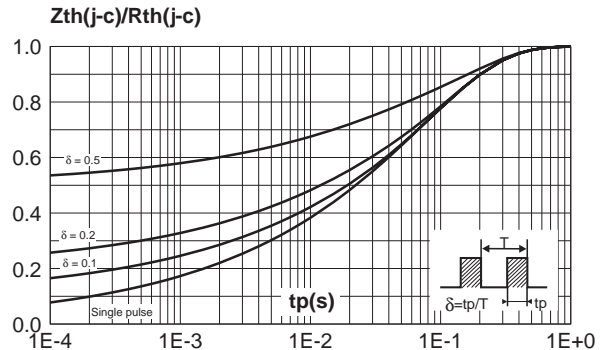


Fig. 6: Reverse leakage current versus reverse voltage applied (typical values) (per diode).

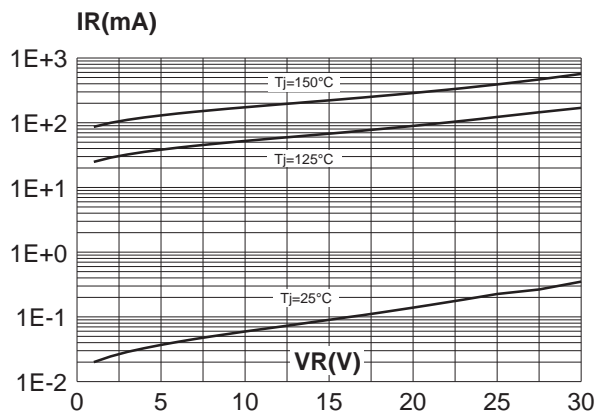


Fig. 7: Junction capacitance versus reverse voltage applied (typical values) (per diode).

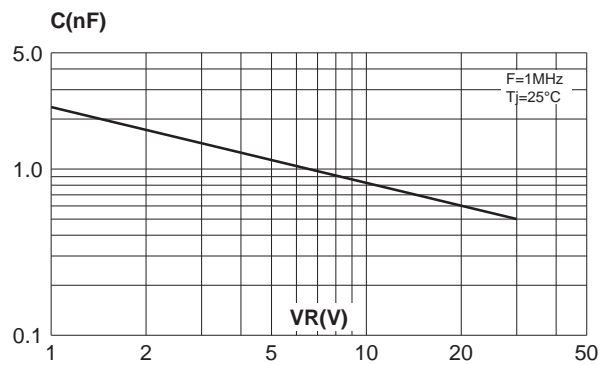


Fig. 8: Forward voltage drop versus forward current (maximum values - per diode).

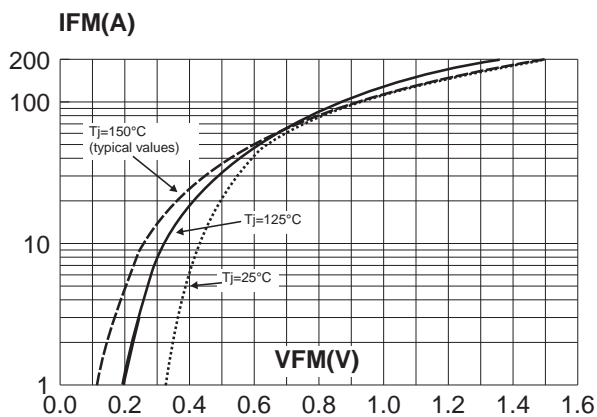
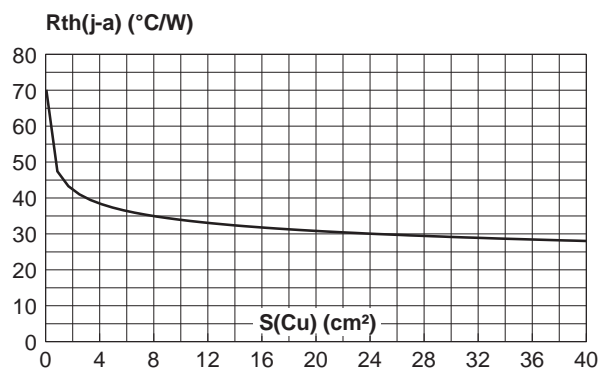
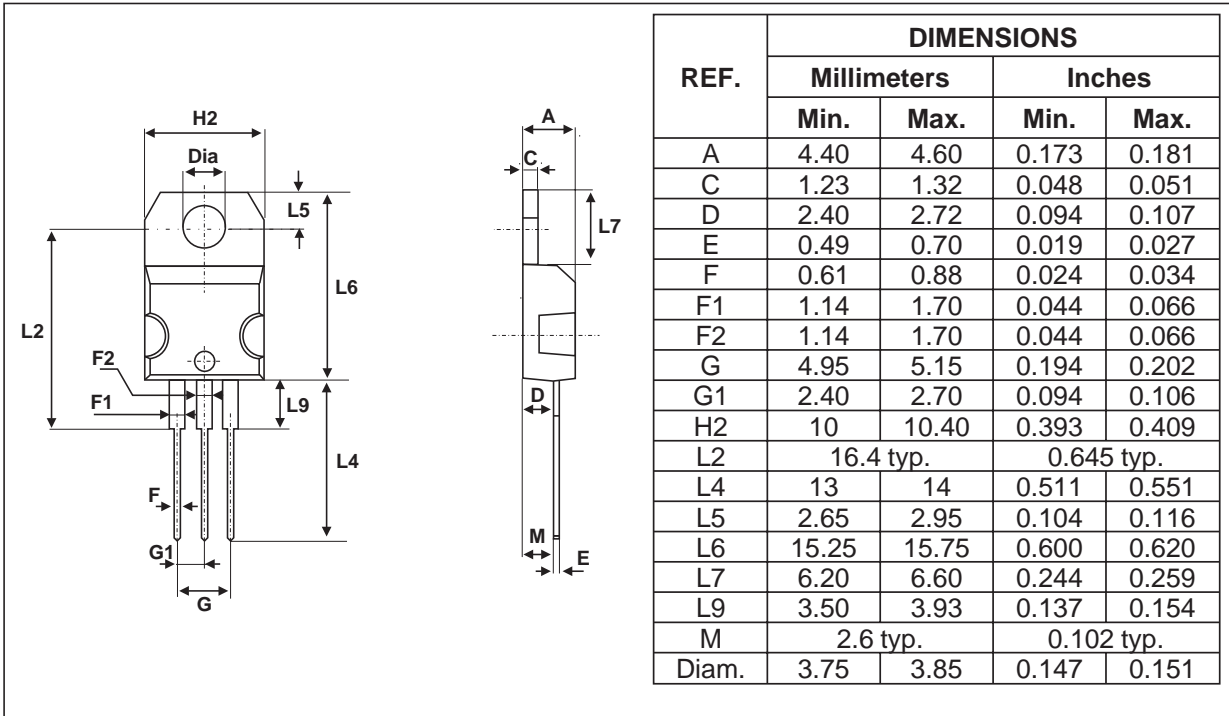


Fig. 9: Thermal resistance junction to ambient versus copper surface under tab (epoxy printed circuit board FR4, e(Cu) = 35 μm) (STPS30L30CG).



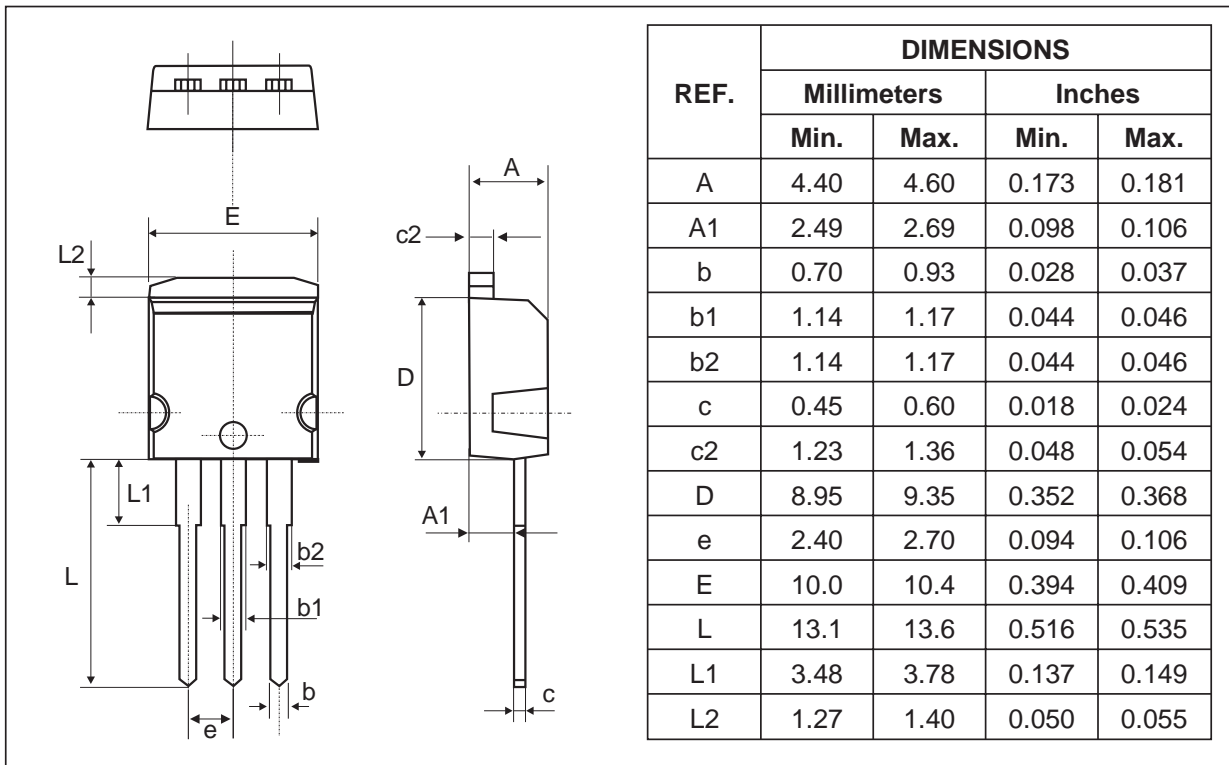
STPS30L30CT/CG/CR

PACKAGE MECHANICAL DATA TO-220AB

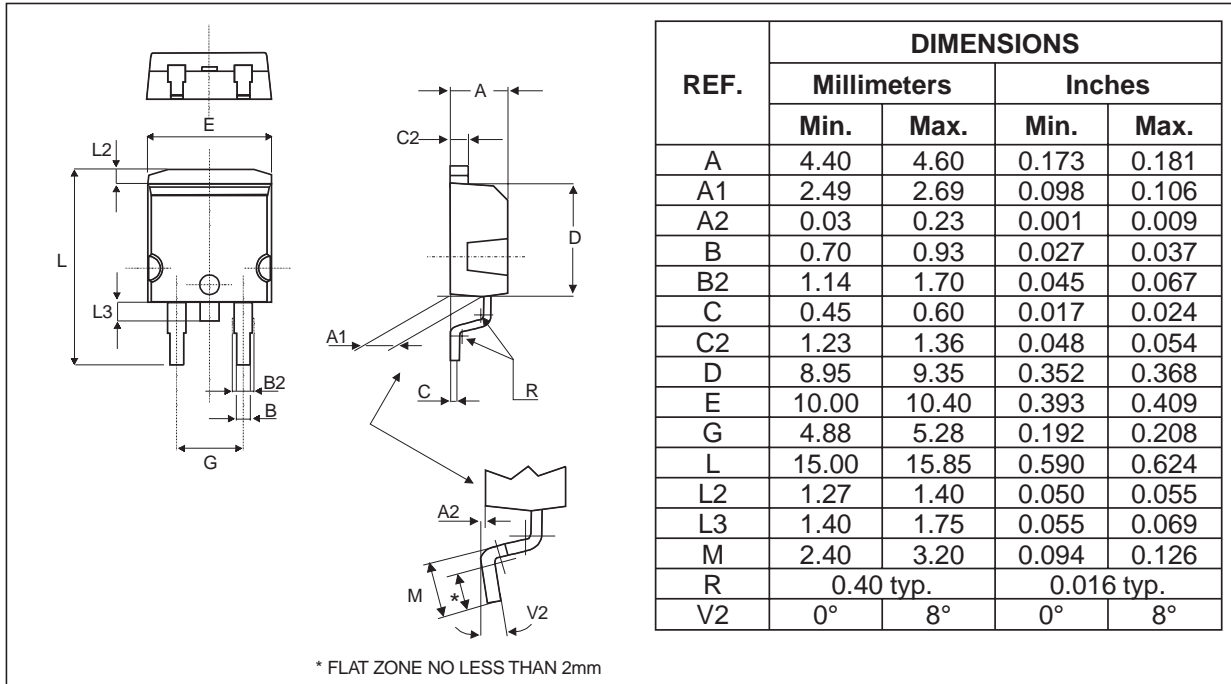


- Cooling method: C
- Recommended torque value: 0.55 m.N
- Maximum torque value: 0.70 m.N

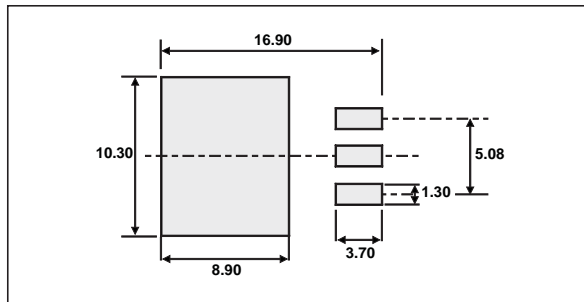
PACKAGE MECHANICAL DATA I²PAK



PACKAGE MECHANICAL DATA
D²PAK



FOOT PRINT (in millimeters)



| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|----------------|-------------|--------------------|--------|----------|---------------|
| STPS30L30CT | STPS30L30CT | TO-220AB | 2g | 50 | Tube |
| STPS30L30CG | STPS30L30CG | D ² PAK | 1.8g | 50 | Tube |
| STPS30L30CG-TR | STPS30L30CG | D ² PAK | 1.8g | 1000 | Tape & reel |
| STPS30L30CR | STPS30L30CR | I ² PAK | 1.49g | 50 | Tube |

- Epoxy meets UL94,V0

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